NSN 5962-00-434-3046

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View Online at https://aerobasegroup.com/nsn/5962-00-434-3046

Body Outside Diameter:

Between 0.335 inches and 0.370 inches

Body Height:

Between 0.165 inches and 0.180 inches

Maximum Power Dissipation Rating:

500.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Monolithic and hermetically sealed and high gain and negative outputs and positive outputs and low power

Inclosure Material:

Glass and metal

Inclosure Configuration:

Can

Input Circuit Pattern:

2 input

Case Outline Source And Designator:

T0-99 joint electron device engineering council

Terminal Surface Treatment:

Gold

Voltage Rating And Type Per Characteristic:

22.0 volts power source

Time Rating Per Chacteristic:

300.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Rom

Precious Material And Location:

Terminal surface gold

Precious Material:

Gold

Test Data Document:

30221-44a340319 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

8 pin

Shelf Life:

N/a

Unit Of Measure:

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- **Demilitarization:**
- Yes demil/mli

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